

# Product Introduction

**GURC01**

**Ultrasonic Radar Chip**

# 1 Product characteristics

## ■ Memory

- MTP: Nonvolatile memory, 8-bit width, 9Bytes, storing calibration data (OSC calibration data, user-defined data, amplifier gain configuration and other parameters), ID
- Volatile memory: Store register values

## ■ Clock

- OSC: 12MHz oscillator, supporting user calibration

## ■ Power supply and power supply management

- $V_{SUP}$  range: 6V~18V
- Support  $V_{SUP}$  overvoltage detection and undervoltage detection
- $V_{DDD}$  range: 4.5V~5.5V
- $V_{DDA}$  range: 3.1V~3.5V
- POR threshold: 4.5V
- Support standby mode

## ■ Sensor driver

- The measurement mode supports the receiving mode and the transmitting mode
- Programmable sensor frequency: 30kHz~83kHz
- Driving current of programmable transformer: 187mA~404mA

## ■ Receiver

- Front end of receiving analog, including PGA, AAF and ADC
- PGA: Programmable amplifier, with 36~50dB analog amplification
- AAF: Anti-alias filter, with DC gain of 2.3 times, and unit gain bandwidth of 200kHz

- ADC: 12bit, 1MHz sampling rate, significant bit not less than 8bit

## ■ Signal processor

- Digital filter
- Digital amplifier: Digital amplifier can be configured, supporting sensitivity time control (STC)
- Echo detection: Support static threshold generation, automatic threshold generation (ATG), echo width detection, echo peak detection (EPD), signal enhancement through fast time constant algorithm (FTC), near-field threshold generation (NFTG), and time measurement

## ■ Communication interface

- 3-wire bidirectional communication interface, flexible communication protocol
- Transmission command and data
- Obtain envelope curve
- Obtain echo detection signal

## ■ Built-in temperature sensor

## ■ JTAG debugging interface

## ■ Application

- Ultrasonic parking assist system (USPA, PAS, etc.)
- Industrial distance measurement

## ■ Encapsulation type

- QFN20

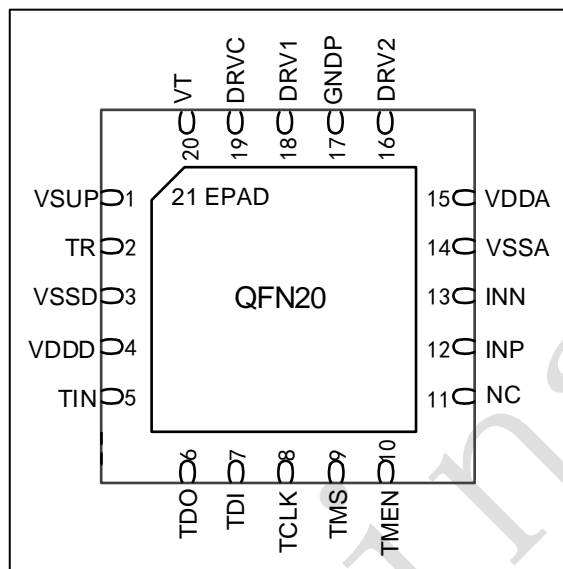
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## 2 Pin information

### 2.1 Pin distribution

Figure 1 Distribution Diagram of GURC01 Series QFN20 Pins



## 3 Functional Description

GURC01 is an ultrasonic sensor driver chip, which is used to drive the ultrasonic sensor to generate ultrasonic wave, receive and process echo signal, and realize the function of object distance detection. It is mainly used in ultrasonic parking assist system (USPA, PAS, etc.) and industrial distance measurement.

The chip is mainly composed of the memory, clock, power supply, sensor driver, receiver, signal processor and communication interface. This chapter mainly introduces the system architecture of GURC01 series products and the functions of each module.

### 3.1 Overview

#### 3.1.1 Principle of ultrasonic distance measurement

Ultrasonic distance measurement is to detect the distance between objects by generating and receiving ultrasonic waves.

The sensor generates an ultrasonic pulse, which will be reflected and received when an object is detected. The distance  $S$  between the sensor and the object, the time duration between the sensor generating and receiving the ultrasonic wave is  $t$ ,  $v$  is the velocity of sound ( $v=343\text{m/s}$ ), and the distance  $S$  can be obtained by the following formula:

$$S = v * t / 2$$

### 3.1.2 Measurement period

Perform an ultrasonic ranging operation cycle using IC as follows:

(1) Measurement of noise

The ambient noise is measured Automatically. Compare the measured noise level with the threshold value, and the measurement information is transmitted to the ECU after the measurement.

(2) Generate wave signal

The ultrasonic measurement cycle starts the measurement using the SND (send) or REC (receive) command.

(3) Sample envelope data

The sensor generates the wave signal and sends it out. When an object is detected, the signal will be reflected back. The reflected pulse is compared with the programmable threshold or automatic threshold after amplifying by the receiver, analog-to-digital conversion and signal processing.

(4) Detection of obstacles

If the echo pulse exceeds the set threshold, the TR line will be pulled down and the signal will be transmitted to the control unit. The time from transmitting the pulse signal to receiving the pulse signal can be calculated, and it is proportional to the distance from the object.

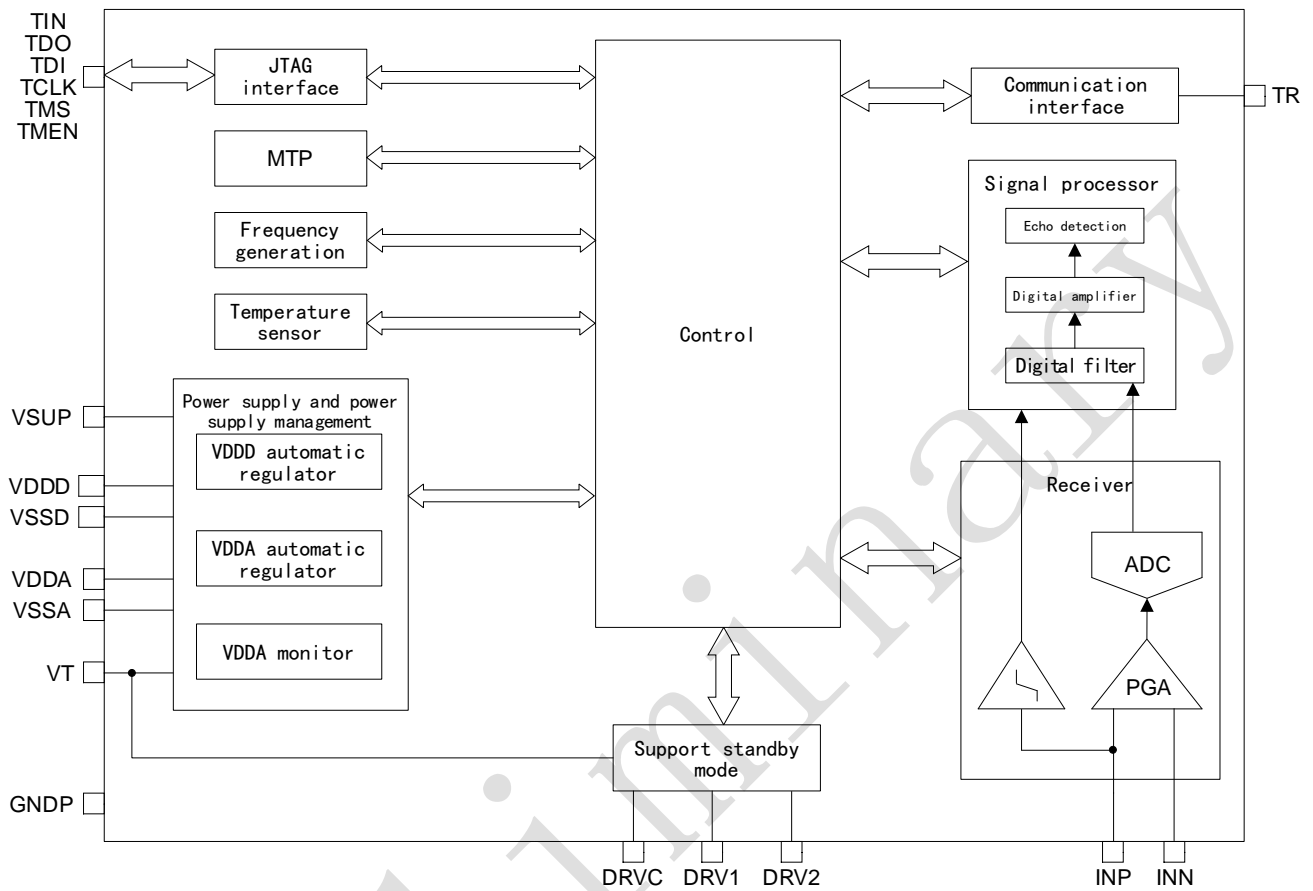
(5) ECU receives diagnostic information

The abnormal state during communication is transmitted to ECU.

Once an ultrasonic measurement cycle is started, it cannot be interrupted. If no measurement is performed, it will be idle.

## 3.2 System architecture block diagram

Figure 2 GURC01 System Architecture Block Diagram



## 4 Electrical characteristics

### 4.1 Test conditions of electrical characteristics

All time values are based on the typical values of the typical oscillator frequency  $f_{osc}$ . All voltages refer to GNDP. The current flowing into the terminal is positive, while the current flowing out from the terminal is negative.

#### 4.1.1 Maximum and minimum values

Unless otherwise stated, the maximum and minimum values are based on the operating conditions of  $V_{SUP} = +6V$  to  $+18V$  and  $T_A = -40^{\circ}C$  to  $+105^{\circ}C$ .

#### 4.1.2 Typical value

Unless otherwise stated, the typical values are based on the operating conditions of  $V_{SUP}=12V$  and  $T_A=+25^{\circ}C$ .

### 4.2 Recommended operating conditions

Table 1 Recommended Operating Conditions

Symbol	Parameter	Minimum value	Maximum value	Unit
$f_{DRV}$	Frequency of sensor driver	38	72	kHz
$V_{SUP}$	Supply voltage	6	18	V
$V_{INP}/V_{INN}$	DC input voltage of pins INP and INN	-1.0	1.0	
$I_{INP}/I_{INN}$	Current of input pins INP and INN	-20	20	mA

### 4.3 Absolute maximum rated value

The stress exceeding the following absolute maximum ratings may cause permanent damage to the equipment. They are only pressure ratings; not implying that the equipment operates under these conditions or any other conditions other than those listed in the operation part of this document. Reliability of the equipment may be affected if it is exposed to the absolute maximum rated conditions for a long time.

#### 4.3.1 Maximum temperature characteristics

Table 2 Maximum Temperature Characteristics

Symbol	Condition	Description	Value	Unit
$T_A$	-	Ambient temperature	-40~+105	$^{\circ}C$
$T_J$	-	Junction temperature	-40~+125	
$T_{STG, welded}$	No tape, welded to PCB	Welding storage temperature	-55~+125	

Symbol	Condition	Description	Value	Unit
T <sub>STG, unwelded</sub>	Unwelded	Unwelded storage temperature in the tape	-40~35	

### 4.3.2 Maximum rated voltage characteristics

Table 3 Maximum Rated Voltage Characteristics

Symbol	Condition	Description	Minimum value	Maximum value	Unit
V <sub>SUP</sub>	-	Supply voltage	-0.3	36	V
V <sub>SUP</sub>	t<500ms	Supply voltage	-0.3	40	
V <sub>TR</sub>	-	Voltage of pin TR	-0.3	36	
V <sub>TR</sub>	t<500ms	Voltage of pin TR	-0.3	40	
V <sub>D</sub>	-	Voltage of pins TIN, TDO, TDI, TCLK, TMS and TMEN	4.5	5.5	
V <sub>INP/VINN</sub>	-	Voltage of pins INP and INN	-1.5	1.5	
V <sub>DDD</sub>	-	Internal digital power supply voltage	4.5	5.5	
V <sub>DDA</sub>	-	Internal analog power supply voltage	3.1	3.5	
V <sub>DRV1, VDRV2, VDRVC, VT</sub>	-	Voltage of pins DRV1, DRV2, DRVC and VT	-0.3	40	

### 4.3.3 ESD protection

Table 4 ESD Characteristics

Symbol	Parameter	Condition	Maximum value	Unit
VESD(HBM)	Pins VSUP and TR	Test as per AEC-Q100-002 (HBM) chip level	TBD	kV
	Other pins		TBD	kV
VESD(CDM)	Pin near the corner (Pins 1, 5, 6, 10, 11, 15, 16, and 20)	Test as per AEC-Q100-011 (CDM) chip level	TBD	V
	Other pins		TBD	V

### 4.3.4 Static latch-up

Table 5 Static Latch Characteristics

Symbol	Parameter	Condition	Type
LU	Static latch-up	T <sub>A</sub> =+25°C/105°C, according to JEDEC standard JESD 78	TBD

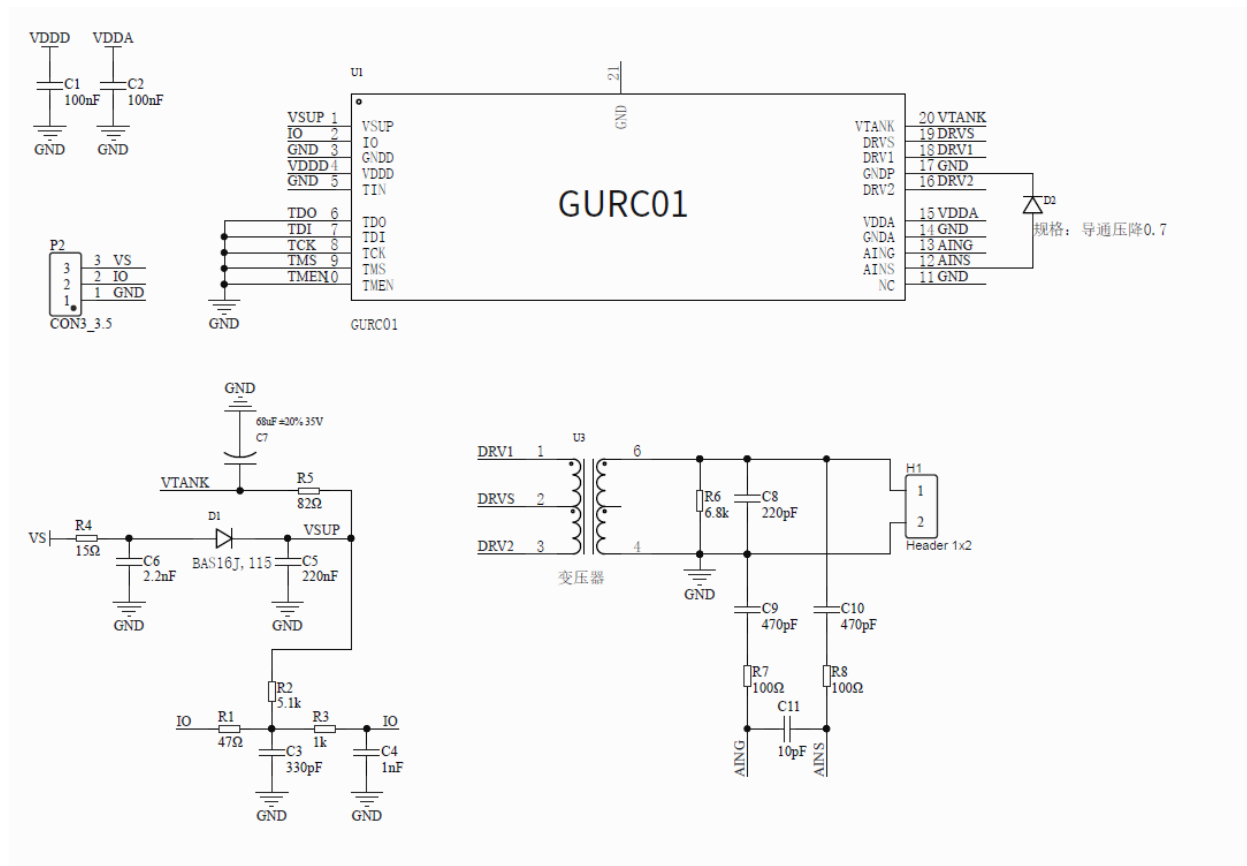


## 5 Typical application

### 5.1 Typical application circuit

ECU and ultrasonic module are connected by three wires, namely GND, VSUP and DATA.

Figure 3 Typical Circuit of GURC01



## 6 Package information

Figure 4QFN20 Encapsulation Diagram

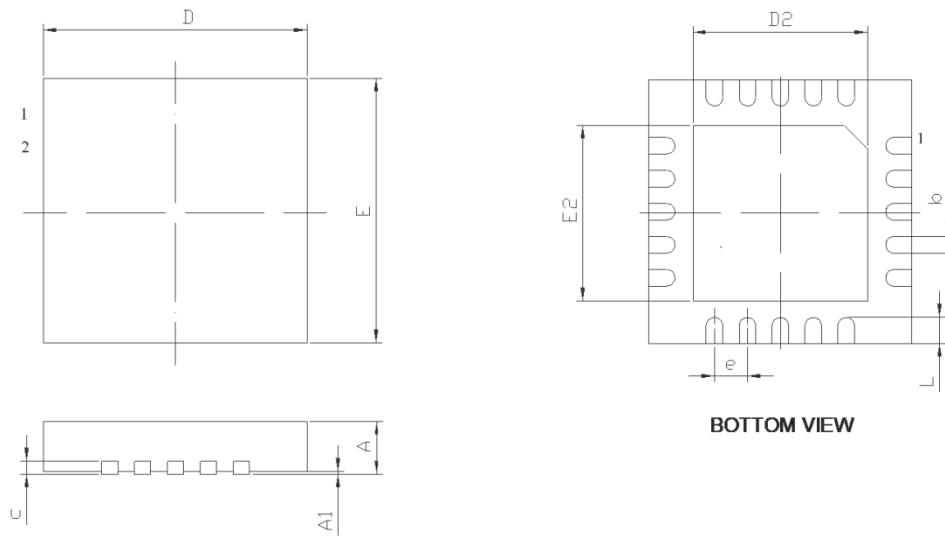


Table 6 Encapsulation Data

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	-	0.02	0.05
b	0.18	0.25	0.30
c	0.18	0.20	0.25
D	3.90	4.00	4.10
D2	2.55	2.65	2.75
e	0.50		
E	3.90	4.00	4.10
E2	2.55	2.65	2.75
L	0.35	0.40	0.45

Note: The mm value is valid, and the inch value includes round-off error.

Figure 5 QFN20-4 x4 Recommended Welding Layout

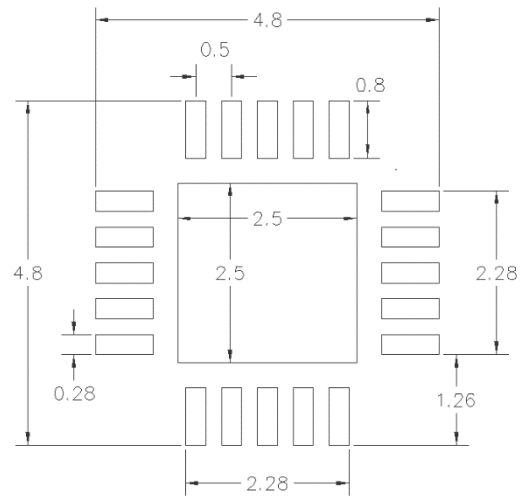
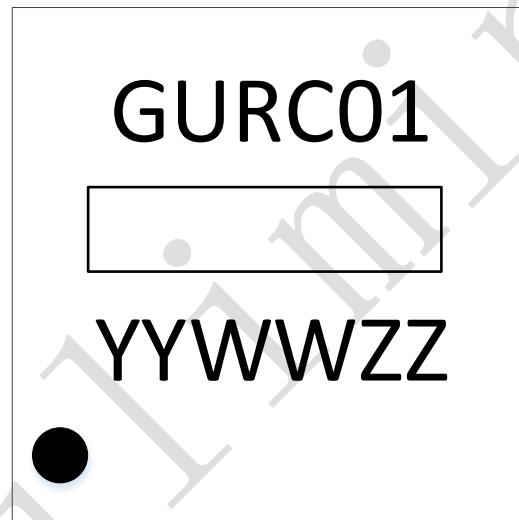


Figure 6 Identification Diagram

Product  
mode



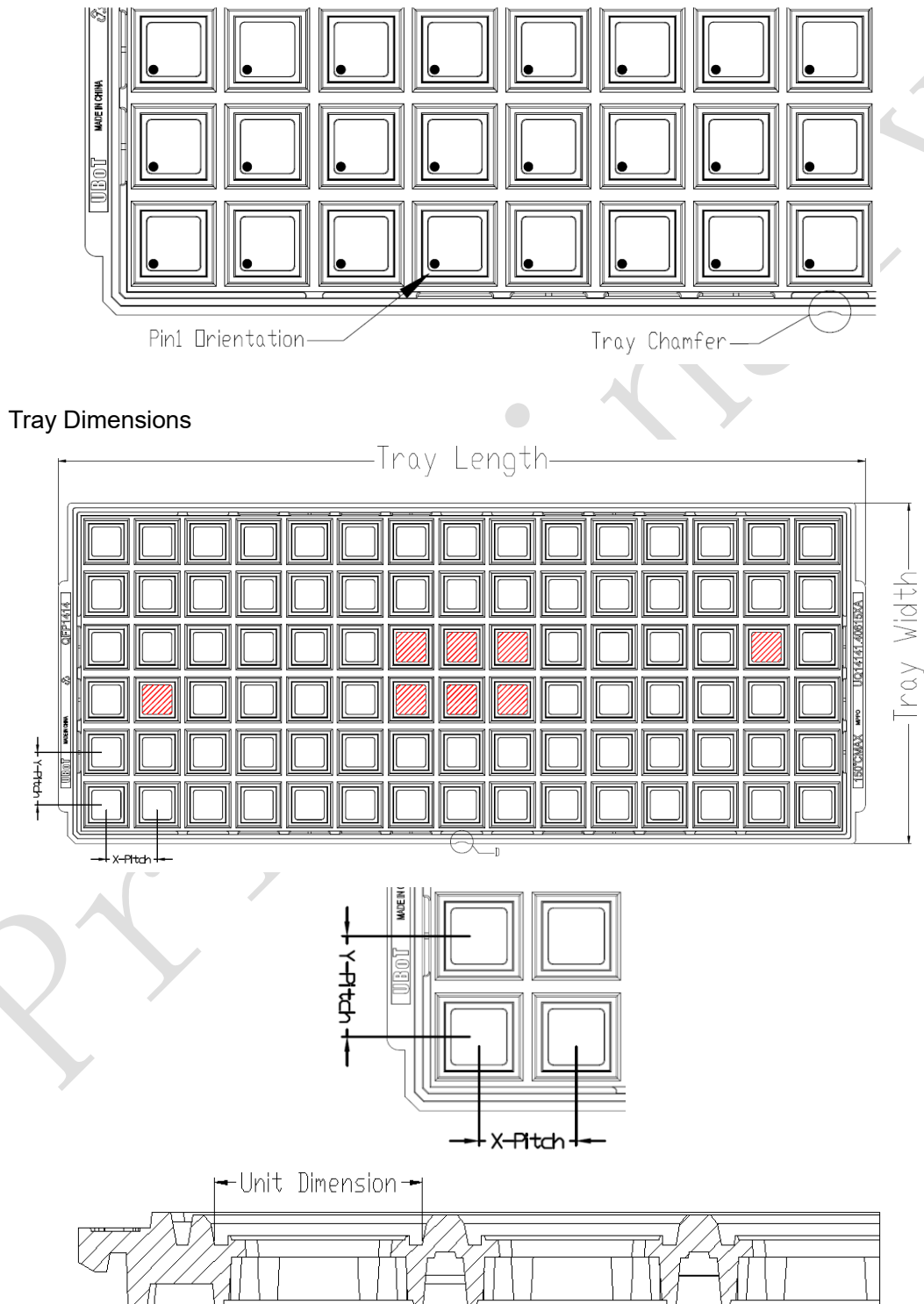
YYWW: Year and week  
number

ZZ: Version number

## 7 Packaging information

### 7.1 Pallet packaging

Figure 7 Pallet Packaging Diagram



All photos are for reference only, and the appearance is subject to the product

Table 7 Pallet Packaging Parameter Specification Table

Device	PKG Type	Pins	SPQ	X-Dimension	Y-Dimension	X-Pitch	Y-Pitch	Tray Length	Tray Width
GURC01	QFN	20	4900	4.2	4.2	8.8	9.2	322.6	135.9

Preliminary

## 8 Ordering information

Table 8 Ordering Information Table

Order Code	Interface	SPQ	Packaging	Temperature range
GURC01	3 wires	4900	QFN20	-40°C to +105°C

Preliminary